

Abstract Submitted
for the MAR14 Meeting of
The American Physical Society

Pseudo-spin Winding Number in Hydrogenated Graphene

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[1] J. Guillemette et al, PRL 110, 176801 (2013).

[2] J.N Fuchs et al Eur. Phys. J. B 77, 351-362 (2010).

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Date submitted: 14 Nov 2013

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